

**Description**

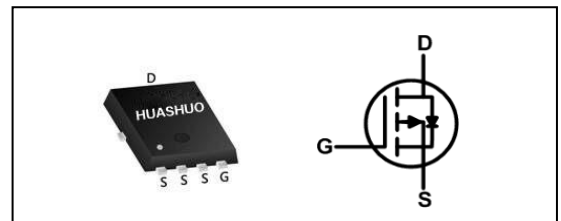
The HSBA100P03 is the high cell density trenched P-ch MOSFETs, which provide excellent RDS(on) and gate charge for most of the synchronous buck converter applications.

The HSBA100P03 meet the RoHS and Green Product requirement, 100% EAS guaranteed with full function reliability approved.

- Super Low Gate Charge
- 100% EAS Guaranteed
- Green Device Available
- Excellent CdV/dt effect decline
- Advanced high cell density Trench technology

**Product Summary**

V <sub>DS</sub>	-30	V
R <sub>DS(ON),typ</sub>	2.6	mΩ
I <sub>D</sub>	-100	A

**PRPAK5X6 Pin Configuration**

**Absolute Maximum Ratings**

Symbol	Parameter	Rating	Units
V <sub>DS</sub>	Drain-Source Voltage	-30	V
V <sub>GS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ -10V <sub>1,6</sub>	-100	A
I <sub>D</sub> @T <sub>C</sub> =100°C	Continuous Drain Current, V <sub>GS</sub> @ -10V <sub>1,6</sub>	-64	A
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup>	-400	A
EAS	Single Pulse Avalanche Energy <sup>3</sup>	310	mJ
I <sub>AS</sub>	Avalanche Current	-80	A
P <sub>D</sub> @T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup>	140	W
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C
T <sub>J</sub>	Operating Junction Temperature Range	-55 to 150	°C

**Thermal Data**

Symbol	Parameter	Typ.	Max.	Unit
R <sub>θJA</sub>	Thermal Resistance Junction-ambient <sub>1</sub> (t ≤ 10S)	---	20	°C/W
	Thermal Resistance Junction-ambient <sub>1</sub> (Steady State)	---	62	°C/W
R <sub>θJC</sub>	Thermal Resistance Junction-case <sub>1</sub>	---	0.9	°C/W

**Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
B <sub>VDS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	---	---	V
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance <sub>2</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-30A	---	2.6	3.3	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-20A	---	3.8	5	mΩ
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =-250uA	-1.2	---	-2.2	V
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =-24V, V <sub>GS</sub> =0V, T <sub>J</sub> =25°C	---	---	-1	uA
		V <sub>DS</sub> =-24V, V <sub>GS</sub> =0V, T <sub>J</sub> =55°C	---	---	-5	
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	---	---	±100	nA
Q <sub>g</sub>	Total Gate Charge (-10V)	V <sub>DS</sub> =-24V, V <sub>GS</sub> =-10V, I <sub>D</sub> =-10A	---	140	---	nC
Q <sub>gs</sub>	Gate-Source Charge		---	22	---	
Q <sub>gd</sub>	Gate-Drain Charge		---	31	---	
T <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> =-15V, V <sub>GS</sub> =-10V, R <sub>G</sub> =5Ω, I <sub>D</sub> =-10A	---	17	---	ns
T <sub>r</sub>	Rise Time		---	60	---	
T <sub>d(off)</sub>	Turn-Off Delay Time		---	200	---	
T <sub>f</sub>	Fall Time		---	111	---	
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =-25V, V <sub>GS</sub> =0V, f=1MHz	---	7900	---	pF
C <sub>oss</sub>	Output Capacitance		---	980	---	
C <sub>rss</sub>	Reverse Transfer Capacitance		---	500	---	

**Diode Characteristics**

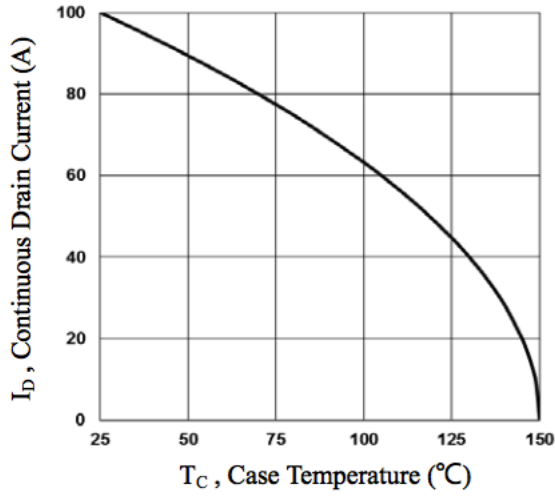
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I <sub>S</sub>	Continuous Source Current <sub>1,5</sub>	V <sub>G</sub> =V <sub>D</sub> =0V, Force Current	---	---	-100	A
V <sub>SD</sub>	Diode Forward Voltage <sub>2</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =-1A, T <sub>J</sub> =25°C	---	---	-1	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> =-20A, di/dt=100A/μs,	---	53	---	nS
Q <sub>rr</sub>	Reverse Recovery Charge	T <sub>J</sub> =25°C	---	52	---	

Note :

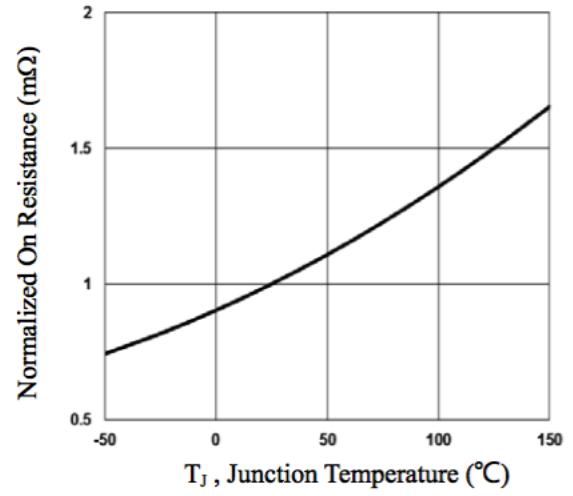
- 1.The data tested by surface mounted on a 1 inch<sub>2</sub> FR-4 board with 2OZ copper.
- 2.The data tested by pulsed, pulse width ≤ 300us, duty cycle ≤ 2%
- 3.The EAS data shows Max. rating. The test condition is V<sub>DD</sub>=-50V, V<sub>GS</sub>=-10V, L=0.1mH, I<sub>AS</sub>=-80A
- 4.The power dissipation is limited by 150°C junction temperature
- 5.The data is theoretically the same as I<sub>D</sub> and I<sub>DM</sub>, in real applications, should be limited by total power dissipation
- 6.The maximum current rating is package limited.



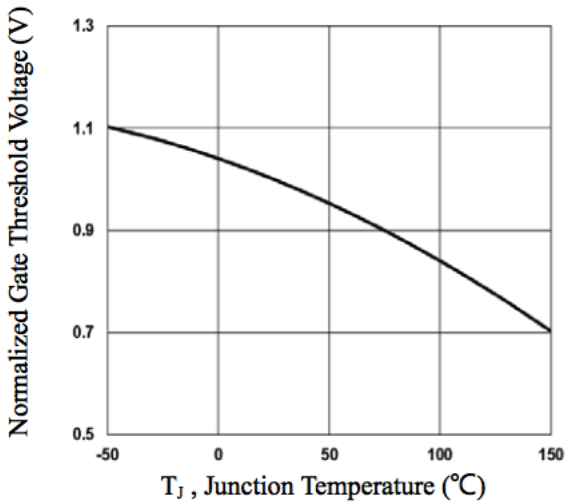
**Typical Characteristics**



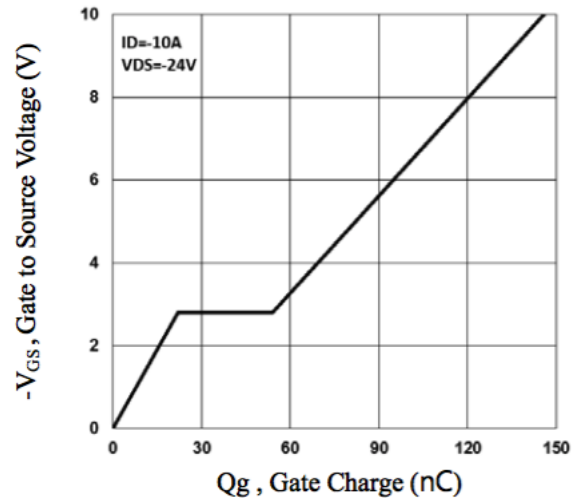
**Fig.1 Continuous Drain Current vs. Tc**



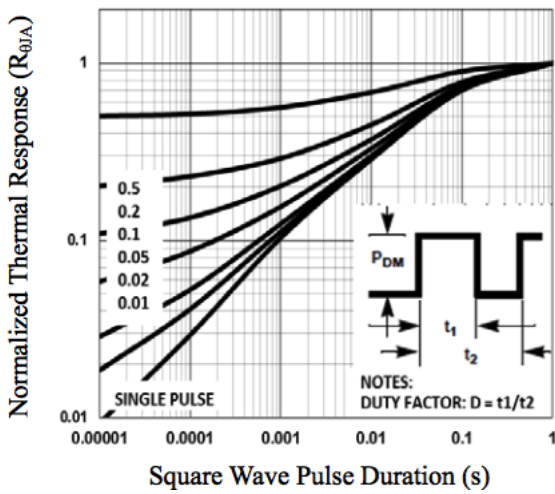
**Fig.2 Normalized RDSon vs. Tj**



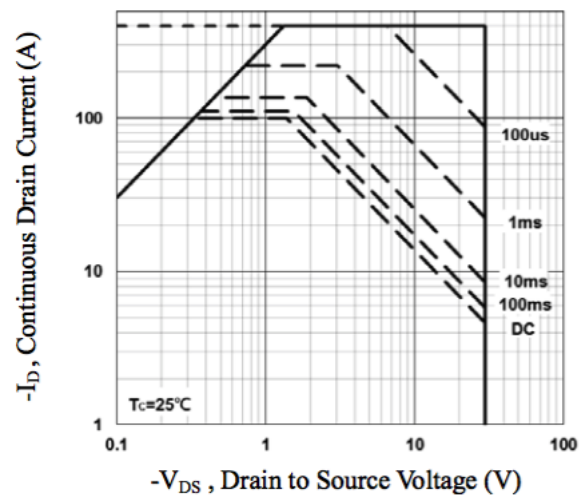
**Fig.3 Normalized Vth vs. Tj**



**Fig.4 Gate-Charge Waveform**



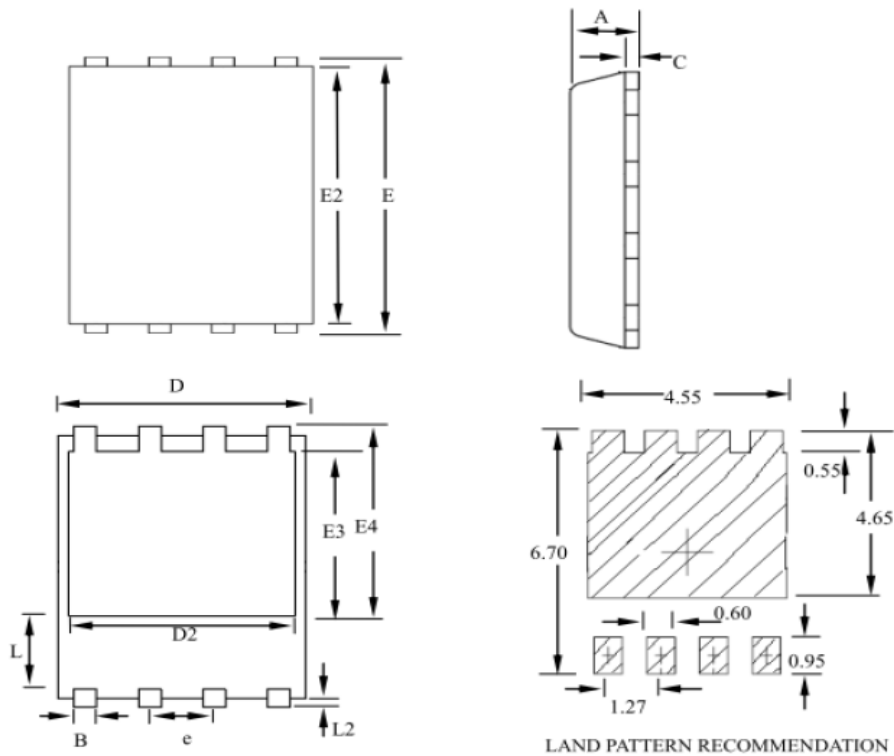
**Fig.5 Normalized Transient Impedance**



**Fig.6 Maximum safe operation Area**

## Ordering Information

Part Number	Package code	Packaging
HSBA100P03	PRPAK5*6	3000/Tape&Reel



SYMBOLS	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.80	--	1.20	0.031	--	0.047
B	0.30	--	0.51	0.012	--	0.020
C	0.15	--	0.35	0.006	--	0.014
D	4.80	--	5.30	0.189	--	0.209
D2	3.61	--	4.35	0.142	--	0.171
E	5.90	--	6.35	0.232	--	0.250
E2	5.42	--	5.90	0.213	--	0.232
E3	3.23	--	3.90	0.127	--	0.154
E4	3.69	--	4.55	0.145	--	0.179
L	0.61	--	1.80	0.024	--	0.071
L2	0.05	--	0.36	0.002	--	0.014
e	--	1.27	--	--	0.050	--

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